

KSC1173

Low Frequency Power Amplifier Power Regulator

- Collector Current : I_C=3A
 Collector Dissipation : P_C=10W (T_C=25°C)
 Complement to KSA473



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
BV _{CBO}	Collector-Base Voltage	30	V
BV _{CEO}	Collector-Emitter Voltage	30	V
BV _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	3	Α
P _C	Collector Dissipation (T _C =25°C)	10	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 500 \mu A, I_E = 0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 10 \text{mA } I_{B} = 0$	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -1 \text{mA}, I_C = 0$	5			
I _{CBO}	Collector Cut-off Current	$V_{CB} = 20V, I_{E} = 0$			1.0	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1.0	μΑ
h _{FE1}	DC Current Gain	$V_{CE} = 2V, I_{C} = 0.5A$	70		240	- 57
h _{FE2}		$V_{CE} = 2V, I_{C} = 2.5A$	25			100
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.2A$	144	0.3	0.8	V
V _{BE} (on)	Base-Emitter ON Voltage	$V_{CE} = 2V, I_{C} = 0.5A$		0.75	1.0	V
f _T	Current Gain Base Width Product	$V_{CE} = 2V, I_{C} = 0.5A$		100		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V$, $I_E = 0$, $f = 1MHz$		35		pF

h_{FE} Classification

Classification	0	Y		
h _{FE1}	70 ~ 140	120 ~ 240		

Typical Characteristics

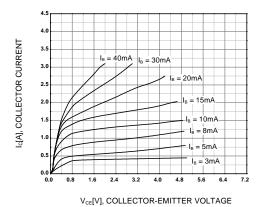


Figure 1. Static Characteristic

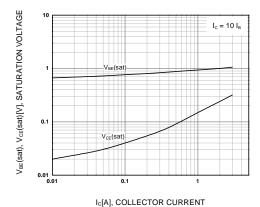


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

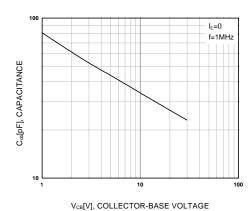


Figure 5. Collector Output Capacitance

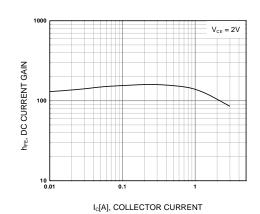


Figure 2. DC current Gain

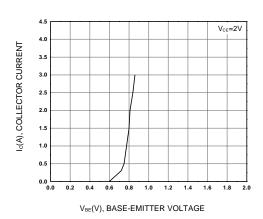


Figure 4. Base-Emitter On Voltage

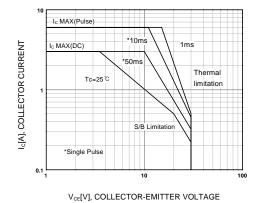


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

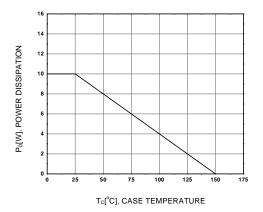
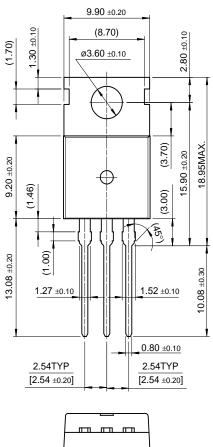


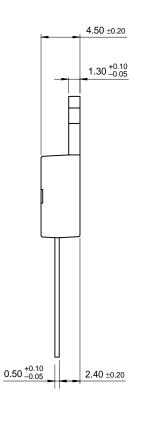
Figure 7. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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